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WIDE BANDWIDTH, HIGH LINEARITY LOW NOISE AMPLIFIER/LINEAR DRIVER

Package Style: QFN, 20-Pin, 5mmx5mm



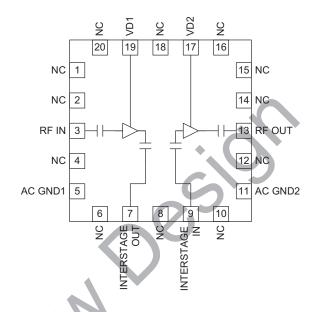


Features

- Low Noise and High Intercept Point
- Adjustable Bias Current for Enhanced IP3
- Single 2.5V to 6.0V Power Supply
- 400 MHz to 3800 MHz Operation
- QFN20, 5mmx5mm Package

Applications

- First Stage WiMAX LNA/Linear Driver
- GSM900, CDMA, PCS, UMTS LNA/Linear Drive
- WLAN LNA
- High Gain Linear Amplification



Functional Block Diagram

Product Description

The RF3866 is a low noise amplifier with a high output IP3. The amplifier is self-biased from a single voltage supply with 50Ω input and output ports. The useful frequency range is from 400MHz to 3800MHz. A 0.8dB noise figure and 36dBm OIP3 performance is achieved with a 5V $V_{\rm DD}$, 180mA. Current can be increased to raise OIP3 while having minimal effect on noise figure. The IC is featured in a standard QFN, 20-pin, $5\,\rm mmx5\,mm$ package.

Ordering Information

RF3866 Wide Bandwidth, High Linearity Low Noise Amplifier/Linear

Driver

RF3866PCK-410 Fully Assembled Evaluation Board with 5 Sample Parts

1.8 GHz to 3.8 GHz

Optimum Technology Matching® Applied

☐ GaAs HBT	☐ SiGe BiCMOS	▼ GaAs pHEMT	☐ GaN HEMT
☐ GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	☐ RF MEMS
☐ InGaP HBT	☐ SiGe HBT	☐ Si BJT	☐ LDMOS

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Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	6	V
Input RF Level (See Note 1)	+10	dBm
Current Drain, I _{DD}	150 per stage	mA
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Junction Temperature (T _J)	150	°C
ESD Rating - Human Body Model (HBM)	Class 1B	
Moisture Sensitivity Level	MSL2	

Note 1. Max continuous RF IN is $\pm 10\,\mathrm{dBm}$. The max transient RF IN is $\pm 20\,\mathrm{dBm}$.



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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Parameter	Specification			Unit	Condition		
raiailietei	Min.	Min. Typ. M		Onit	Condition		
High Band							
Frequency	3300		3800	MHz			
Current		180	220	mA	V _{DD} =5V		
Gain		20		dB	+25°C, V _{DD} =5V, I _{DD} =180 mA, 3500 MHz unless specified		
Noise Figure		0.9		dB			
Output IP3		37		dBm	f ₁ =3500 MHz, f ₂ =3501 MHz		
Output P1dB		22		dBm			
S11		-15		dB			
S22		-17		dB			
S12		-33		dB			
Mid Band							
Frequency	1800		2700	MHz			
Current		180	220	mA	V _{DD} =5V		
Gain	28	30	32	dB	+25°C, V _{DD} =5V, I _{DD} =180 mA, 2000 MHz unless specified		
Noise Figure		0.8	1.0	dB			
Output IP3	34	36		dBm	f ₁ =2000 MHz, f ₂ =2001 MHz		
Output P1dB	21.0	22.5	25.0	dBm			
S11		-10		dB			
\$22		-16		dB			
\$12		-40		dB			
Low Band							
Frequency	700		1100	MHz			
Current		180	220	mA	V _{DD} =5V		
Gain		32		dB	+25 °C, V _{DD} =5V, I _{DD} =180 mA, 850 MHz unless specified		
Noise Figure		1.0		dB			
OIP3		37		dBm	f ₁ =850MHz, f ₂ =851MHz		
OP1dB		22.5		dBm			
S11		-10		dB			
S22		-12		dB			



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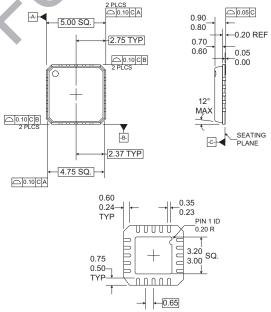
S12		-48		dB			
Thermal							
Theta _{JC}		30		°C/W	Dissipated power=V _{DD} *(I _{DD1} +I _{DD2})		
Dovomotov		Specification			O a ve distinue		
Parameter	Min.	Тур.	Max.	Unit	Condition		
Thermal							
Theta _{JC}		30		°C/W	Dissipated power=V _{DD} *(I _{DD1} +I _{DD2})		
Power Supply							
Device Operating Voltage	2.5	5.0	6.0	V			
Operating Current	130	180	220	mA	V _{DD} =5V, R3=open		

RF3866



Pin	Function	Description
1	NC	Not connected.
2	NC	Not connected.
3	RF IN	RF input pin. 50Ω matched. This pin is DC-blocked.
4	NC	Not connected.
5	AC GND1	AC ground. Shunt cap may be added for tuning.
6	NC	Not connected.
7	INTERSTAGE	Interstage RF output. This signal is brought off-chip in case a bandpass filter is needed.
	OUT	
8	NC	Not connected.
9	INTERSTAGE	Interstage RF input.
	IN	*
10	NC	Not connected.
11	AC GND2	AC ground. Shunt resistor may be added to increase I _{DD} and OIP3.
12	NC	Not connected.
13	RF OUT	RF output pin. 50Ω matched. This pin is DC-blocked
14	NC	Not connected.
15	NC	Not connected.
16	NC	Not connected.
17	VD2	Bias voltage. 2.5V to 6.0V applied through bias inductor.
18	NC	Not connected.
19	VD1	Bias voltage. 2.5V to 6.0V applied through bias inductor.
20	NC	Not connected.
Pkg	GND	Ground connection and heat sink.
Base		

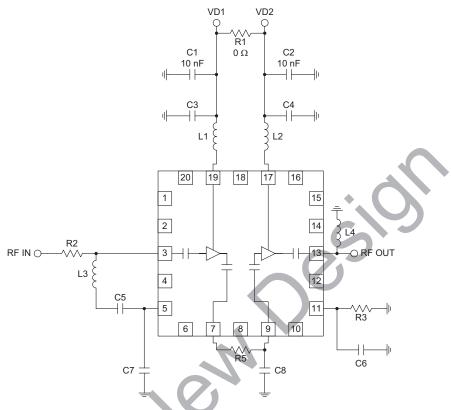
Package Drawing



Dimensions in mm.



Evaluation Board Schematic

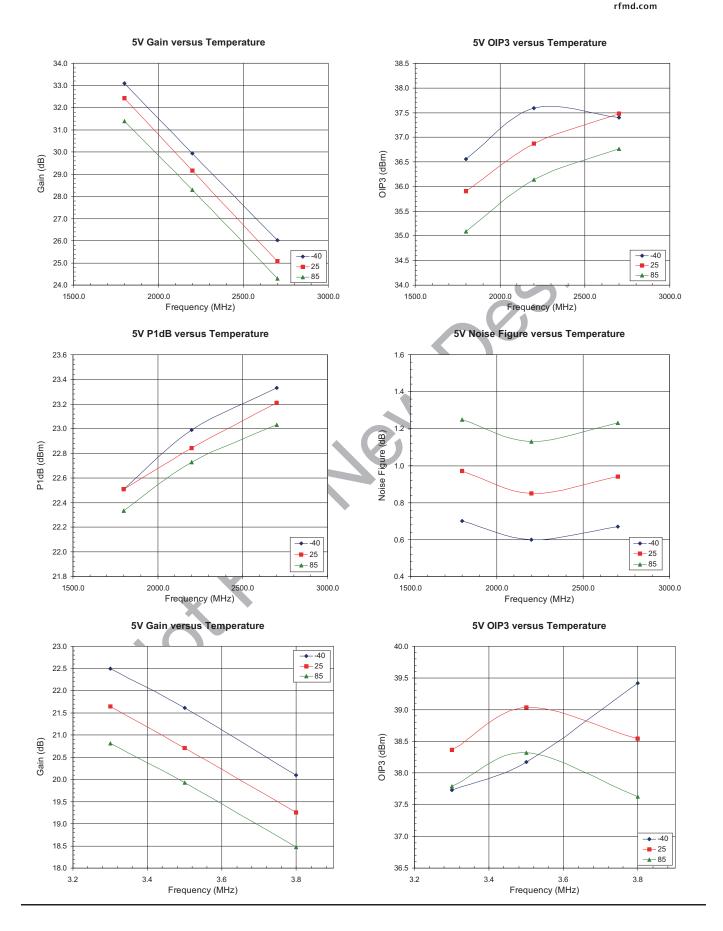


R3 is DNP for standard 180mA current draw. If R3 is added, the I_{DD} will increase. A 20Ω R3 will raise the current to achieve higher linearity.

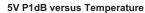
Components	700MHz to 1100MHz	1.8GHz to 3.8GHz
L1 (nH)	12	8.2
L2 (nH)	8.2	4.7
L3 (nH)	18	4.7
L4 (nH)	DNP	DNP
C3 (pF)	10	18
C4 (pF)	10	18
C5 (pF)	100	100
C6 (pF)	DNP	DNP
C7 (pF)	DNP	10
C8 (pF)	DNP	0.5
R2 (Ω)	0	0
R3 (Ω)	DNP	DNP
R5 (Ω)	6.8pF	15 pF

RF3866

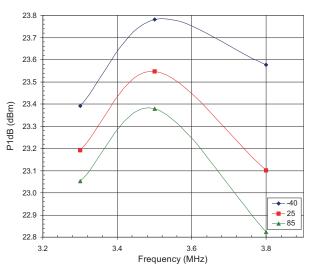


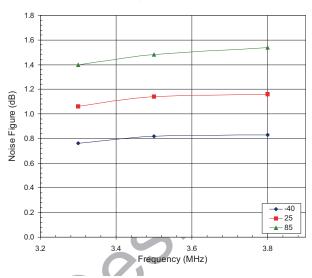




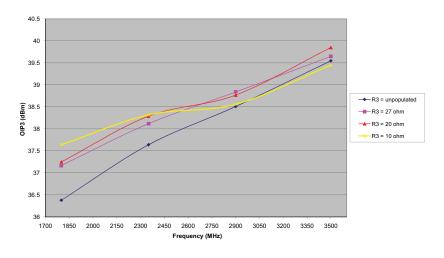


5V Noise Figure versus Temperature



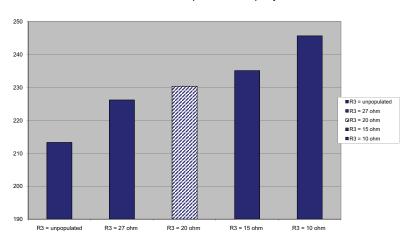


RF3866-410 1800 - 3800 MHz Evaluation Board OIP3 vs R3 value R3 = 20 ohm sees best trade-off vs frequency



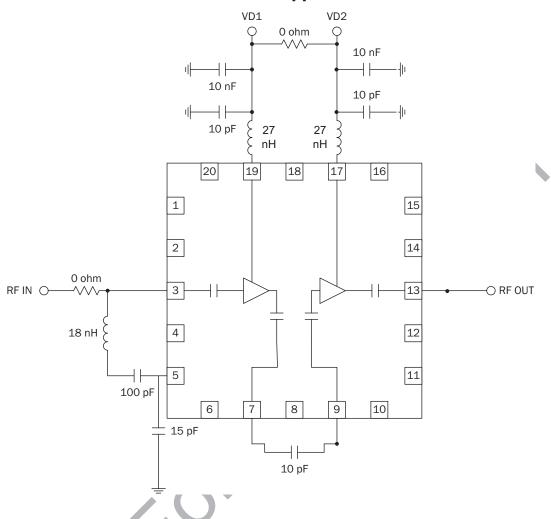


RF3866-410 1800 - 3800 MHz Evaluation Board Icc vs R3 value R3 = 20 ohm for optimum IP3 vs Frequency





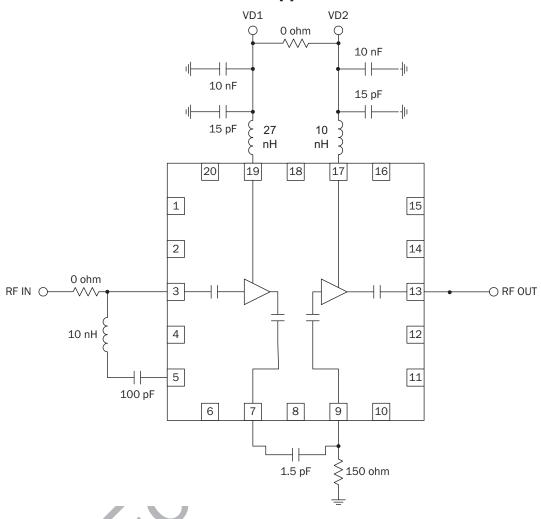
400 MHz to 1000 MHz Application Schematic



Frequency	VCC	ICC	Gain	OIP3	OP1dB	NF
MHz	V	mA	dB	dBm	dBm	dB
400	5	174.532	32.69	36.02	22.08	1.75
600	5	174.513	34.48	37.93	22.31	1.45
800	5	174.456	33.06	37.89	21.9	1.1
1000	5	174.585	30.77	37.17	22	1.25



700 MHz to 2200 MHz Application Schematic



Frequency	VCC	ICC	Gain	OIP3	OP1dB	NF
MHz	V	mA	dB	dBm	dBm	dB
700	5	174.687	27.02	35.53	22.15	1.45
1200	5	174.876	26.14	36.76	21.99	1
1700	5	174.903	26.22	35.49	21.38	0.85
2200	5	174.918	24.99	36.13	22.15	0.85

RF3866



Theory of Operation

Low noise figure and high gain/IP3 make RF3866 ideal for use as both a receive LNA and a transmit driver for cellular/DCS/PCS/UMTS and WiMax platforms, in addition to many other general purpose applications. Standard evaluation boards cover 700 MHz to 1100 MHz and 1800 MHz to 3800 MHz. Viewing the data sheet evaluation board schematic, refer below for purpose and function of external components:

- R2/L4/C6 (0Ω/unpopulated/unpopulated on standard evaluation boards): These unused components were placed for convenience and flexibility when needed to optimize matching for an out of band application.
- L3/C5/C7: Place to optimize input match and enhance out of band low frequency stability.
- R3: Optionally placed to increase bias current and IP3. 20Ω value is found to be the best case (see graph section).
- L1/C3/R5/C8: Interstage tuning.
- L2/C4: Influence output return loss.

RF3866 has internal DC-blocking capacitors at RFin/RFout. In addition, it has been shown that impedance seen looking out at pins 7/9/17/19 influence response. As a result, two port s-parameters become non-applicable. if matching is desired for frequency bands outside of those provided with standard evaluation boards, application schematics within this data sheet for 400 MHz to 1000 MHz and 700 MHz to 2200 MHz serve as examples.

Detailed discussion of each begins here with the 400 MHz to 1000 MHz schematic. In this application the design goals were as follows:

- Input and output return loss better than 10dB over the entire 600MHz bandwidth.
- IP3 and compression point in line with standard evaluation board performance.

These goals were attained, with additional specifications shown in tabular data accompanying schematic:

- Noise figure = 1.75 dB to 1.25 dB versus frequency
- Gain = 32.7 dB to 30.8 dB at band edges.

To extend the standard 700MHz to 1100MHz evaluation board response down to 400MHz, the following components were changed (refer to reference designators in evaluation board schematic):

- C7 adjusted from unpopulated to 15 pF
- L1 adjusted from 12nH to 27nH
- L2 adjusted from 8.2 nH to 27 nH
- "R5" adjusted from 6.8 pF to 10 pF

In effect, all components were placed or increased in value to shift response down in frequency. Broadband characteristic of the part allowed return loss/performance to extend out to 1000MHz.

Next, consider the application schematic shown for 700 MHz to 2200 MHz. The design goals in this case:

- Maintain noise figure/IP3/OP1dB within reason to that seen on standard board.
- Obtain 2dB gain flatness over the 1500MHz bandwidth, along with better than 10dB input/output return loss.



Again, start with the standard 700 MHz to 1100 MHz evaluation board and make the following changes:

- L3 adjusted from 18nH to 10nH
- L1 adjusted from 12 nH to 27 nH
- L2 adjusted from 8.2nH to 10nH
- "R5" adjusted from 6.8 pF to 1.5 pF
- "C8" adjusted from unpopulated to 150Ω
- C3 and C4 adjusted from 10pF to 15pF

Intuitive changes were made at L3 and R5. Lowering L3 extends input match higher in frequency. Lowering "R5" to 1.5 pF helps meet gain flatness specification by reducing gain on the low end of the band.

Non-intuitive changes:

- "C8" value of 150Ω optimized interstage match for gain flatness.
- L1/L2/C3/ C4 chosen via trial and error to further influence gain and meet return loss specification.

The above matching discussion should be helpful when considering use in frequency bands outside of those covered by standard evaluation boards. it can be noted here that application schematics and standard boards collectively cover 100% of the usable bandwidth from 400 MHz to 3800 MHz. As such, choosing from these available schematics should accommodate the majority of applications that come about.